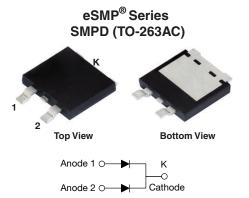
Vishay Semiconductors

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Hyperfast Rectifier, 2 x 10 A FRED Pt[®]



LIKNKS TO ADDITIONAL RESOURCES



SHAY

PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 10 A				
V _R	200 V				
V _F at I _F	0.77 V				
t _{rr}	25 ns				
T _J max.	175 °C				
Package	SMPD (TO-263AC)				
Circuit configuration	Common cathode				

FEATURES

- Hyperfast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, telecom, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage		V _{RRM}		200	V		
Average rectified forward current	per device	I _{F(AV)}	T _{solder pad} = 152 °C	20	A		
Average rectified forward current	per diode			10			
Non-repetitive peak surge current	per device		T_J = 25 °C, 6 ms square pulse	210			
	per diode	IFSM		110			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	200	-	-		
Forward voltage, per diode	V _F	I _F = 10 A	-	0.94	1.05	V	
		I _F = 10 A, T _J = 150 °C	-	0.77	0.87		
Reverse leakage current, per diode	I _R	V _R = V _R rated	-	-	2	μA	
		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	10	150		
Junction capacitance, per diode	CT	V _R = 200 V	-	30	-	pF	

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COMPLIANT

HALOGEN



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		I _F = 1 A, dI _F /dt = 50 A	õs, V _R = 30 V	-	25	-	
Reverse recovery time	+	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		-	-	25	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	22	-	- ns - A
		T _J = 125 °C		-	35	-	
Pools receivers ourrent		T _J = 25 °C	$I_{\rm F} = 10 {\rm A},$	-	2.5	-	
Peak recovery current	IRRM	T _J = 125 °C	dl _F /dt = 200 A/µs, V _B = 160 V	-	5	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	25	-	nC
		T _J = 125 °C]	-	85	-	nc

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C
Thermal resistance, per diode junction to mount	R _{thJM}		-	1.8	2.4	°C/W
Approximate weight				0.55		g
Approximate weight				0.02		oz.
Marking device		Case style SMPD (TO-263AC)		20CI	DH02	

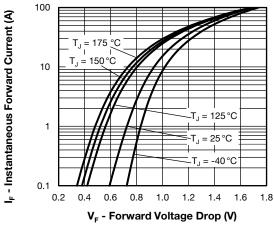
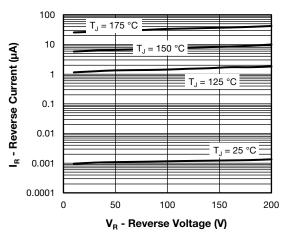


Fig. 1 - Typical Forward Voltage Drop Characteristics





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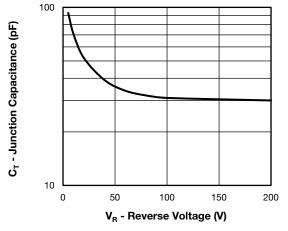


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

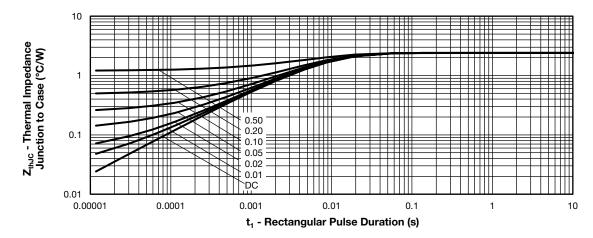
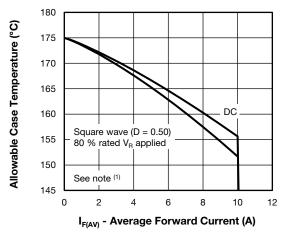
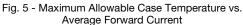


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Average Power Loss (W)

14







(1)

Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 5); Pd_{REV} = inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = rated V_R

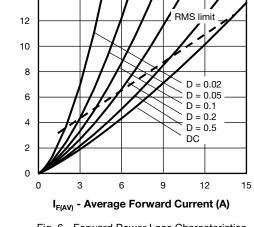


Fig. 6 - Forward Power Loss Characteristics

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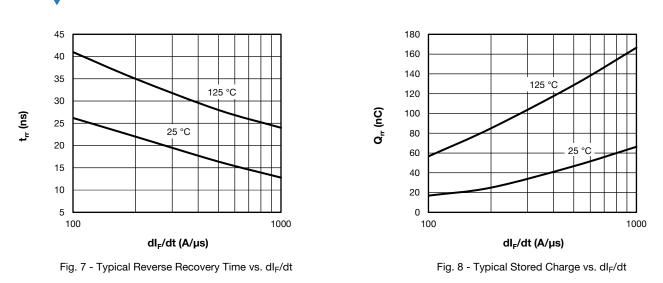
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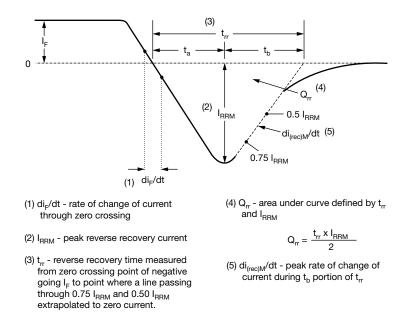


Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

VISHAY

Device code	VS-	20	С	D	н	02	Н	M 3
	1	2	3	4	5	6	7	8
	1	- Vis	hay Sen	nicondu	ctors pr	oduct		
	2	- Cur	rent rati	ing (20 A	4)			
	3	- Circ	cuit con	figuratio	n:			
		C =	commo	on catho	de			
	4	- D =	SMPD	package	е			
	5	- Pro	cess typ	ce,				
		H =	hyperfa	ast recov	very			
	6	- Vol	tage coo	de (02 =	200 V)			
	7	- H=	AEC-Q	101 qua	alified			
	8	- M3	= halog	en-free,	RoHS-	complia	ant, and	termina

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-20CDH02HM3/I	2000	2000	13" diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95604				
Part marking information	www.vishay.com/doc?95566				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96572				

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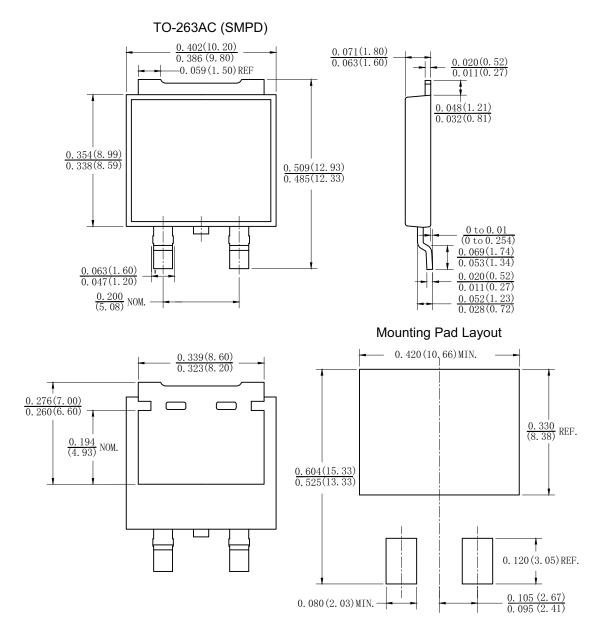


Outline Dimensions

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TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)





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